Disappearing of the Ir-ordered state in the Pyrochlore iridates (Nd,Ca)₂Ir₂O₇ studied by μ SR

R. Asih, *1,*2 S. S. Mohd-Tajudin, *1,*3 N. Adam, *1,*3 K. Matsuhira, *4 T. Nakano, *2 Y. Nozue, *2 and I. Watanabe *1,*2,*3

Pyrochore iridates, $R_2 Ir_2 O_7$ (R-227, R = Y and rare-earth element), are an ideal platform to study the interplay between electron correlation (U) and spinorbit coupling (SOC) in which the electron correlation (U) can be systematically tuned by changing the ionic radius of R-ion (r).¹⁾ Among pyrochlore systems, these compounds have the widest structure stability²) and experimentally have revealed systematic metalinsulator transition (MIT) and systematic variation of properties with $R^{(3)}$ The MIT temperature, $T_{\rm MI}$, decreases monotonically as the ionic radius of R^{3+} increases, and its boundary lies between R = Nd and Pr.³⁾ Accordingly the study on a change in the magnetically ordered state in $Nd_2Ir_2O_7$ and its doped-systems is important to discuss an intrinsic critical behavior of the electronic state in R_2 Ir₂O₇.

In this study, we report the effect of Ca substitution on the magnetic ordered state of Ir^{4+} spins in Nd₂Ir₂O₇ investigated by muon-spin relaxation. Nd₂Ir₂O₇ shows metallic behavior at high temperature and undergoes MIT at temperatures around 33 K,³⁾ and the magnetic order in this material also seem to occur simultaneously at $T_{\rm MI}$ without any lattice distortion.⁴⁾ In our previous μ SR results on Nd₂Ir₂O₇,⁵⁾ we observed the coherent magnetically ordered state of Ir⁴⁺ spins just below $T_{\rm MI}$ and confirmed that Nd³⁺ moments mainly grew below 15 K as observed in the neutron diffraction.⁶⁾

As observed in the electrical resistivity and the DC magnetization measurements, in which the $T_{\rm MI}$ and magnetic transition $(T_{\rm M})$ decrease by increasing Ca doping, we expected the Ca substitution to dramatically suppress the magnetic order of $\rm Ir^{4+}$ spins in $(\rm Nd_{1-x}Ca_x)_2\rm Ir_2O_7$. Figure 1 shows the zero-field (ZF) time spectrum of $(\rm Nd_{1-x}Ca_x)_2\rm Ir_2O_7$ at a temperature of 1.5 K. The spontaneous muon spin precession is still observed in the sample with 3 % of Ca-doped, and it becomes less well-defined at a higher Ca substitution. A heavily damped muon-spin precession with fast damping rate is the characteristic in the time spectrum at a high Ca concentration. A phenomenological function of

$$A_{(t)} = A_1 e^{-\lambda_1 t} + A_2 e^{-\lambda_2 t} + A_3 \cos(\gamma_\mu H_{int} + \varphi) e^{-\lambda_3 t}$$
(1)

is used to fit the time spectra. λ_1 and λ_2 are the slow

and fast relaxation rates, respectively, while λ_3 is the damping rate of muon-spin precession. H_{int} and φ are the internal field at the muon site and the initial phase of muon precession, respectively.



Fig. 1. Zero-field time spectrum of $(Nd_{1-x}Ca_x)_2Ir_2O_7$ in the early time region at a temperature of 1.5 K. The solid lines are fits to Eq. 1.

A spontaneous muon spin precession was observed in the sample with 3 % of Ca concentration at a temperature below 12.5 K, which is lower than the $T_{\rm MI}$ of this sample. At higher Ca concentrations, x = 0.07and 0.10, no static ordering was observed at temperature below 1.5 K. Although the $T_{\rm MI}$ of these samples is estimated to be approximately 10 K and 5 K, respectively. This indicates that the carrier doping would strongly suppress the magnetic ordering rather than the changes in the electrical transport properties.

References

- 1) X. Wan et al., Phys. Rev. B 83, 205101 (2011).
- 2) J. S. Gardner, M. J. P. Gingras, and J. E. Greedan, Rev. Mod. Phys. 82, 53 (2010)
- K. Matsuhira et al., J. Phys. Soc. Jpn. 80, 094701 (2011).
- J. Yamaura et al., Phys. Rev. Letter 108, 247205 (2012).
- 5) H. Guo et al., Phys. Rev. B 88, 060411(R) (2013).
- K. Tomiyasu et al., J. Phys. Soc. Jpn. 81, 034709 (2012).

^{*1} RIKEN Nishina Center

^{*&}lt;sup>2</sup> Department of Physics, Osaka University

^{*&}lt;sup>3</sup> School of Distance Education, Universiti Sains Malaysia

^{*4} Graduate School of Engineering, Kyushu Institute of Technology